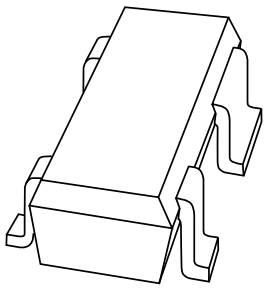
DATA SHEET



BFG21W
UHF power transistor

Product specification
Supersedes data of 1997 Nov 21

1998 Jul 06

UHF power transistor BFG21W

FEATURES

- High power gain
- High efficiency
- 1.9 GHz operating area
- Linear and non-linear operation.

APPLICATIONS

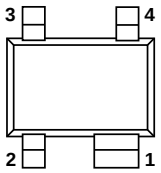
- Common emitter class-AB output stage in hand held radio equipment at 1.9 GHz such as DECT, PHS, etc.
- Driver for DCS1800, 1900.

DESCRIPTION

NPN double polysilicon bipolar power transistor with buried layer for low voltage medium power applications encapsulated in a plastic, 4-pin dual-emitter SOT343R package.

PINNING

PIN	DESCRIPTION
1, 3	emitter
2	base
4	collector



Top view MSB842

Marking code: P1.

Fig.1 Simplified outline SOT343R.

QUICK REFERENCE DATA

RF performance at $T_s \leq 60$ °C in a common emitter test circuit.

MODE OF OPERATION	f (GHz)	V_{CE} (V)	P_L (dBm)	G_p (dB)	η_C (%)
Pulsed class-AB; $\delta < 1 : 2$; $t_p = 5$ ms	1.9	3.6	26	≥10	typ.55

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	15	V
V_{CEO}	collector-emitter voltage	open base	–	4.5	V
V_{EBO}	emitter-base voltage	open collector	–	1	V
I_C	collector current (DC)		–	500	mA
P_{tot}	total power dissipation	$T_s \leq 60$ °C; note 1	–	600	mW
T_{stg}	storage temperature		−65	+150	°C
T_j	operating junction temperature		–	150	°C

Note

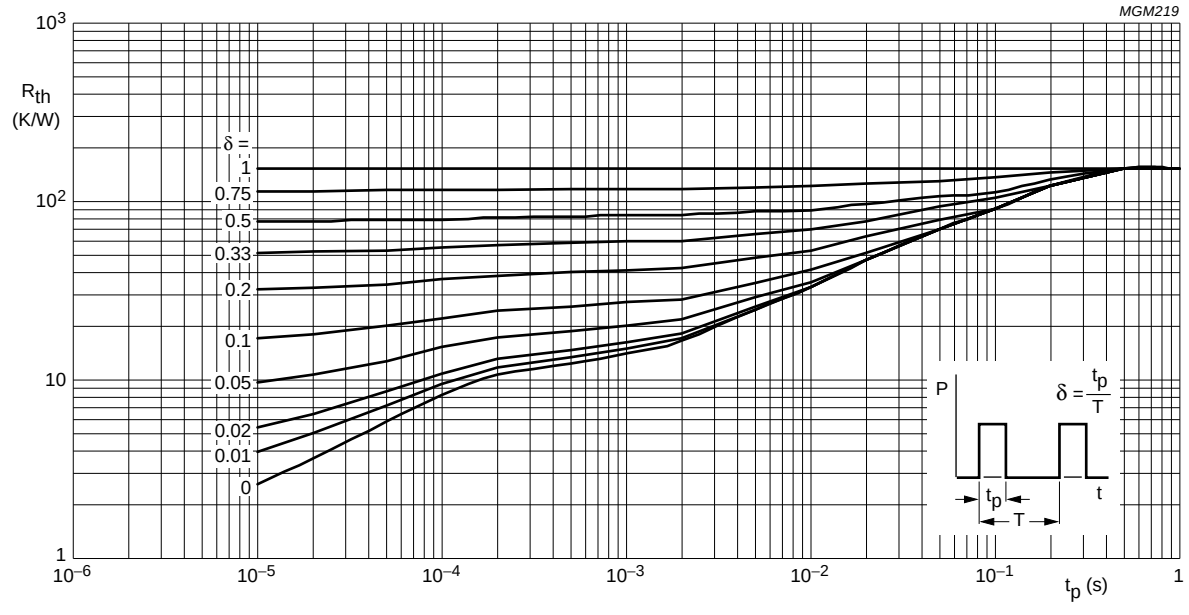
1. T_s is the temperature at the soldering point of the emitter pins.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}s}$	thermal resistance from junction to soldering point	$T_s \leq 60$ °C; P_{tot} = 600 mW; note 1	150	K/W

Note

1. T_s is the temperature at the soldering point of the emitter pins.



At temperature stabilization solder point has been reached.

Fig.2 Transient thermal resistance as a function of pulse time; typical values.

CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	open emitter; I_C = 0.1 mA	15	–	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	open base; I_C = 10 mA	4.5	–	V
$V_{(BR)CER}$	collector-emitter breakdown voltage	R_{BE} < 1 kΩ, I_C = 10 mA	10	–	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	open collector; I_E = 0.1 mA	1	–	V
I_{CES}	collector leakage current	V_{CE} = 5 V; V_{BE} = 0	–	10	μA
h_{FE}	DC current gain	I_C = 200 mA; V_{CE} = 2 V	40	100	
C_c	collector capacitance	I_E = i_e= 0; V_{CB} = 3 V; f = 1 MHz	–	3	pF
C_{re}	feedback capacitance	I_C = 0; V_{CB} = 3.6 V; f = 1 MHz	–	1.5	pF
f_T	transition frequency	I_C = 200 mA; V_{CE} = 3.6 V; f = 700 MHz	18	–	GHz

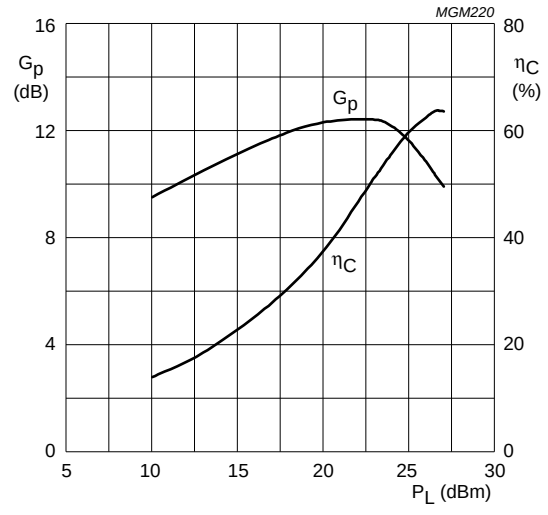
APPLICATION INFORMATION

RF performance at $T_s \leq$ 60 °C in a common emitter test circuit (see Figs 4 and 5).

MODE OF OPERATION	f (GHz)	V_{CE} (V)	I_{CQ} (mA)	P_L (dBm)	G_p (dB)	η_C (%)
Pulsed; class-AB; δ < 1 : 2; t_p = 5 ms	1.9	3.6	1	26	≥10	typ. 55

Ruggedness in class-AB operation

The transistor is capable of withstanding a load mismatch corresponding to VSWR = 6 : 1 through all phases at 26 dBm output power under pulsed conditions: δ = 1 : 2; t_p = 5 ms; f = 1.9 GHz at V_{CE} = 4.5 V.



Pulsed, class-AB operation; δ < 1 : 2; t_p = 5 ms.
f = 1.9 GHz; V_{CE} = 3.6 V; I_{CQ} = 1 mA; tuned at P_L = 26 dBm.

Fig.3 Power gain and collector efficiency as a function of the load power; typical values.

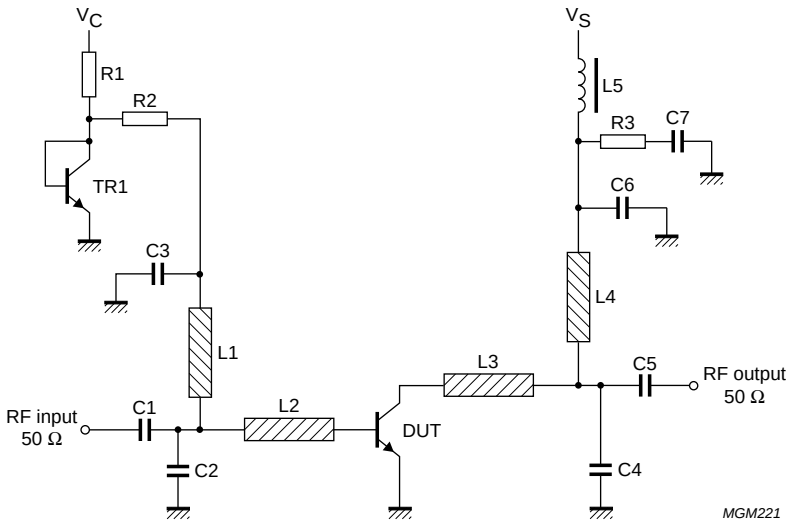


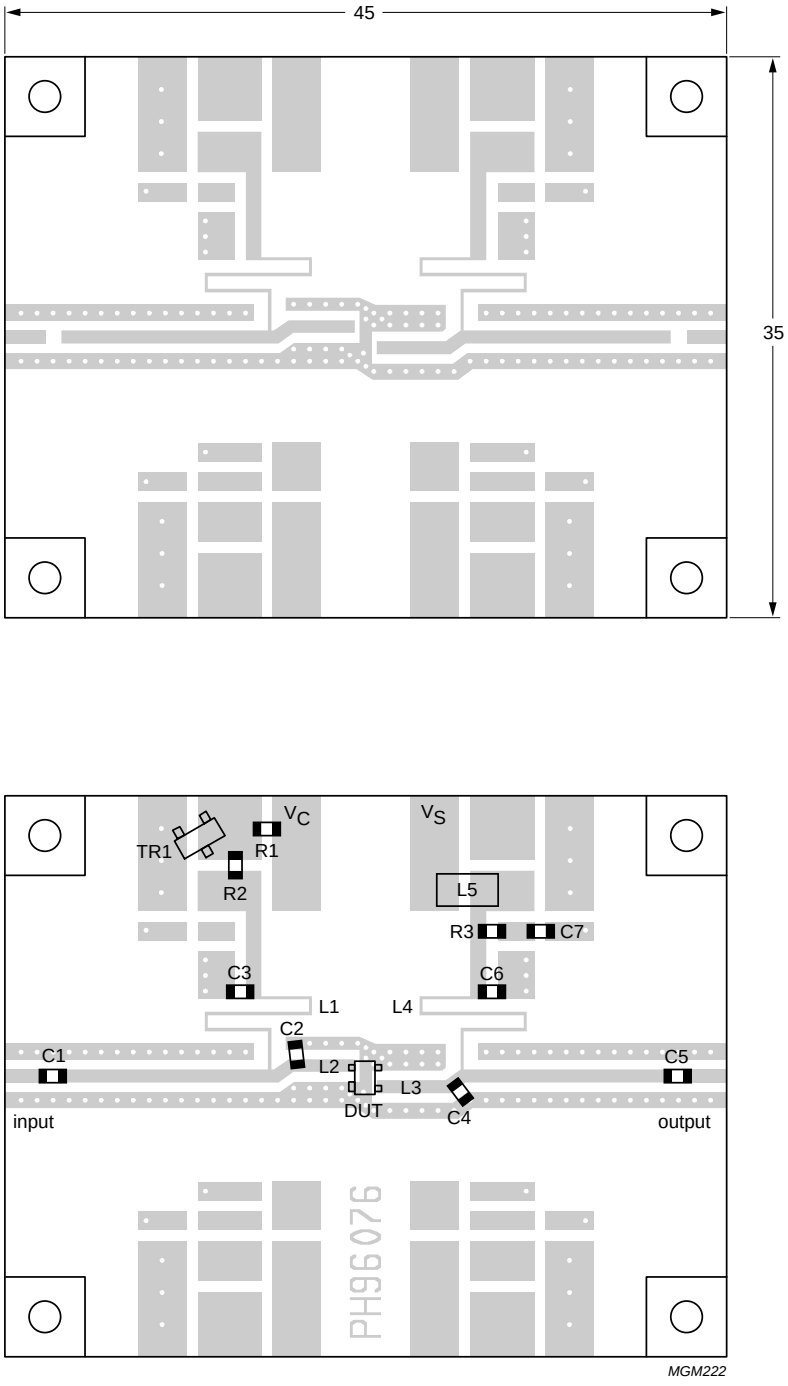
Fig.4 Common emitter test circuit for class-AB operation at 1.9 GHz.

List of components used in test circuit (see Figs 4 and 5)

COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE No.
C1, C5	multilayer ceramic chip capacitor; note 1	24 pF		
C2	multilayer ceramic chip capacitor; note 1	3.3 pF		
C3, C6	multilayer ceramic chip capacitor, note 1	15 pF		
C4	multilayer ceramic chip capacitor; note 1	2.4 pF		
C7	multilayer ceramic chip capacitor; note 1	1 nF		
L1, L4	stripline; note 2	100 Ω	18 × 0.2 mm	
L2	stripline; note 2	50 Ω	3.2 × 0.8 mm	
L3	stripline; note 2	50 Ω	4.6 × 0.8 mm	
L5	Grade 4S2 Ferroxcube chip bead			4330 030 36300
R1	metal film resistor	220 Ω; 0.4 W		
R2, R3	metal film resistor	10 Ω; 0.4 W		
TR1	NPN transistor	BC817		9335 895 20215

Notes

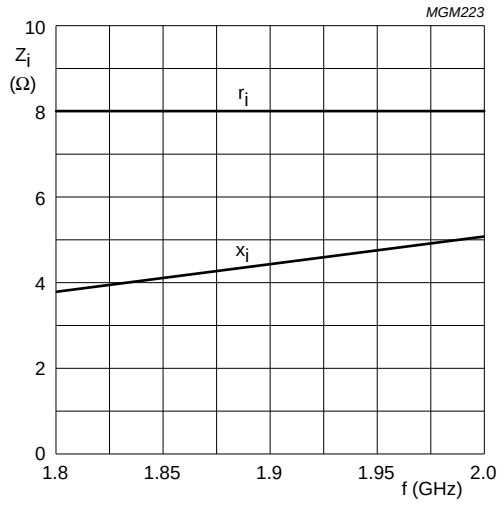
1. American Technical Ceramics type 100A or capacitor of same quality.
2. The striplines are on a double copper-clad printed-circuit board with PTFE fibre-glass dielectric (ε_r = 6.15, tan δ = 0.0019); thickness 0.64 mm, copper cladding = 35 μm.



Dimensions in mm.

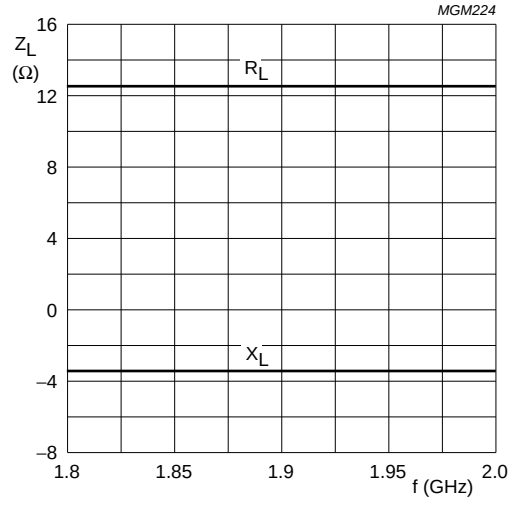
The components are situated on one side of the copper-clad PTFE fibre-glass board, the other side is unetched and serves as a ground plane. Earth connections from the component side to the ground plane are made by through metallization.

Fig.5 Printed-circuit board and component lay-out for 1.9 GHz class-AB test-circuit in Fig.4.



V_{CE} = 3.6 V; I_{CQ} = 1 mA; P_L = 26 dBm; $T_s \leq 60$ °C.

Fig.6 Input impedance as function of frequency (series components); typical values.

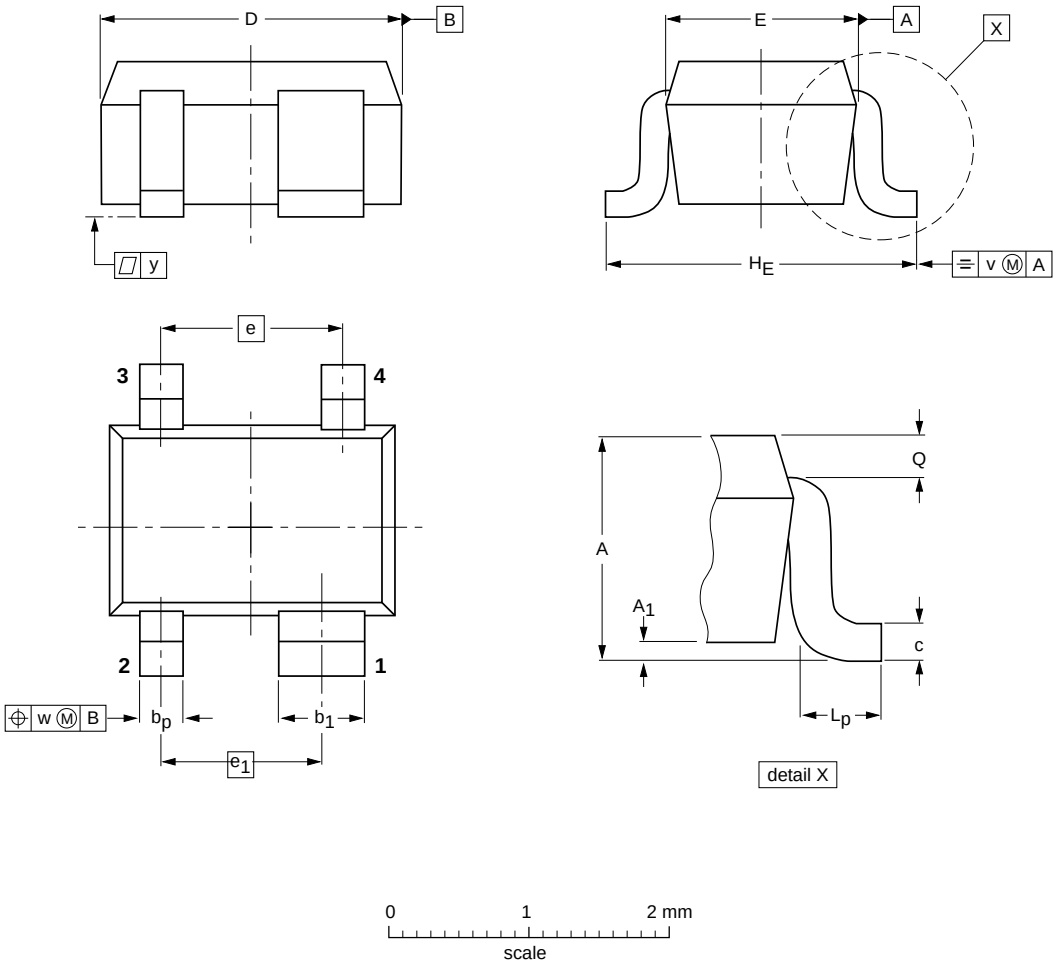


V_{CE} = 3.6 V; I_{CQ} = 1 mA; P_L = 26 dBm; $T_s \leq 60$ °C.

Fig.7 Load impedance as a function of frequency (series components); typical values.

PACKAGE OUTLINE

Plastic surface-mounted package; reverse pinning; 4 leads **SOT343R**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	b_1	c	D	E	e	e_1	H_E	L_p	Q	v	w	y
mm	1.1 0.8	0.1	0.4 0.3	0.7 0.5	0.25 0.10	2.2 1.8	1.35 1.15	1.3	1.15	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT343R						~~97-05-21~~ 06-03-16

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

1. Please consult the most recently issued document before initiating or completing a design.
2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

DEFINITIONS

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

DISCLAIMERS

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

NXP Semiconductors

provides High Performance Mixed Signal and Standard Product solutions that leverage its leading RF, Analog, Power Management, Interface, Security and Digital Processing expertise

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: **http://www.nxp.com**
For sales offices addresses send e-mail to: **salesaddresses@nxp.com**

Printed in The Netherlands R77/03/pp11 Date of release: 1998 Jul 06

littlediode
COMPONENTS FOR ALL

Littlediode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.